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One Dayton Conde	APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	ATTORNEY DOCKET NO. CONFIRMATION NO.	
Killworth, Gottman, Hagan & Schaeff, L.L.P.  Suite 500 One Dayton Centre  LE, THAO X  ART UNIT PAPER NUM	10/044,178	01/10/2002	Todd Edgar	MIO 0011 N2 3193		
Suite 500 One Dayton Centre  ART UNIT PAPER NUM	Killworth, Gottman, Hagan & Schaeff, L.L.P. Suite 500			EXAM	EXAMINER	
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Dayton, OH 45402-2023 2814					TATER NONDER	

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application No.	Applicant(s)		
	0.55	10/044,178	EDGAR, TODD		
	Office Action Summary	Examiner	Art Unit		
		Thao X. Le	2814		
Period fo	The MAILING DATE of this communication ap or Reply	opears on the cover sheet with the c	orrespondence address		
THE - Exter after - If the - If NC - Failu Any	ORTENED STATUTORY PERIOD FOR REPI MAILING DATE OF THIS COMMUNICATION nsions of time may be available under the provisions of 37 CFR 1 SIX (6) MONTHS from the mailing date of this communication. period for reply specified above is less than thirty (30) days, a reperiod for reply is specified above, the maximum statutory period re to reply within the set or extended period for reply will, by staturely received by the Office later than three months after the mailined patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be timply within the statutory minimum of thirty (30) days dwill apply and will expire SIX (6) MONTHS from te, cause the application to become ABANDONE	ely filed s will be considered timely. the mailing date of this communication. O (35 U.S.C. § 133).		
Status					
1)⊠	Responsive to communication(s) filed on 19 l	December 2005.			
2a)⊠	This action is <b>FINAL</b> . 2b) ☐ Th	is action is non-final.			
3)□	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.				
Dispositi	on of Claims				
5)□ 6)⊠ 7)□	Claim(s) <u>1-5</u> is/are pending in the application 4a) Of the above claim(s) is/are withdra Claim(s) is/are allowed. Claim(s) <u>1-5</u> is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction and/	awn from consideration.			
Applicati	on Papers				
10)	The specification is objected to by the Examin The drawing(s) filed on is/are: a) ac Applicant may not request that any objection to the Replacement drawing sheet(s) including the corre The oath or declaration is objected to by the E	cepted or b) objected to by the E e drawing(s) be held in abeyance. See ction is required if the drawing(s) is obj	ected to. See 37 CFR 1.121(d).		
Priority (	ınder 35 U.S.C. § 119				
a)	Acknowledgment is made of a claim for foreig  All b) Some * c) None of:  1. Certified copies of the priority documer  2. Certified copies of the priority documer  3. Copies of the certified copies of the priority application from the International Bureace the attached detailed Office action for a list	nts have been received.  Its have been received in Application or the contraction of the	on No In this National Stage		
Attachmen		o □	(DTO 412)		
2) Notice	te of References Cited (PTO-892) te of Draftsperson's Patent Drawing Review (PTO-948) mation Disclosure Statement(s) (PTO-1449 or PTO/SB/08 or No(s)/Mail Date <u>12/21/05</u> .	4) Interview Summary Paper No(s)/Mail Da  5) Notice of Informal P  6) Other:			

### **DETAILED ACTION**

## Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-5 are rejected under 35 U.S.C. 103(a) as being unpatentable over US 5576240 to Radosevich et al. in view of US 5028990 to Kotaki et al. or US 5108941 to Paterson et al.

Regarding claims 1-2, Radosevich discloses a storage container structure in fig. 1 comprising: a single layer substrate 11, column 2 line 61, including a doped semiconductor structure 12, col. 3 line 35; a single insulating material 13, col. 3 line 25, disposed over and in contact with said substrate, the insulating material 13 of sufficient depth to include a container region (where 14 is located) disposed therein, said container region defining a container cross section having container side walls, a container bottom wall, and a container interior bounded in part by said container side walls and said container bottom wall; a patterning stop region 12 disposed over and in contact with said substrate 11 such that a substantially entirely of the width of said container region is defined by an upper surface of said patterning stop region 12, fig. 1; a charge storage lamina 14/15/17 formed over an interior surface of said container region; said charge storage lamina comprising a first conductive film 14, col. 2 line 63, a

second conductive film 17, col. 2 line 58, defining a first surface thereon, and an insulating film 15, col. 3 line 7, disposed intermediate said first and second conductive films 14/17; a contact region (outer surface of 17) defined by said charge storage lamina, wherein said contact region defines a contact region cross section having contact region side walls and a contact region bottom wall, and wherein said contact region side walls and said contact region bottom wall are defined by said first surface of said second conductive film 17.

But Radosevich does not disclose an electrical contact in contact with said first surface of said second conductive film such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region.

However, Kotaki discloses a storage container structure comprises an electrical contact 16, fig. 10 col. 4 line 68, in contact with said first surface of said second conductive film 14, col. 3 line31, such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region. In addition, Paterson discloses a storage container structure in fig. 2h comprises an electrical contact 30, col. 5 line 28, in contact with said first surface of said second conductive film 24, col. 4 line 38, such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region. At the time the invention was made; it would have been obvious to one of ordinary skill in the art to use the electrical contact teaching of Kotaki and/or Paterson with Radosevich's device, because it would have established an

electrical contact with the top plate electrode and/or allowing the programming and reading as taught by Paterson col. 6 lines 1-10.

Regarding claim 3, Radosevich discloses a storage container structure comprising: a single substrate 11 including a doped semiconductor structure 12, said substrate including a generally planar upper surface; a single insulating material 13 disposed over and in contact with said generally planar upper surface of said substrate 11, said insulating material including a container region disposed therein (where 14 is located), said container region defining a container cross section having container side walls, a container bottom wall, and a container interior bounded in part by container side walls and said container bottom wall; a patterning stop region 12 including: a lower surface disposed over and in contact with said generally planar upper surface of substrate 11; and an upper surface configured such that the lowermost extension of container bottom wall does not project substantially below upper surface of said patterning stop region 12; a charge storage lamina 14/15/17 over an interior surface of said container region; said charge storage lamina comprising a first conductive film 14, a second conductive film 17 defining a first surface thereon, and an insulating film 15 disposed intermediate said first and second conductive films 14/17; a contact region (top surface of 17) defined by said charge storage lamina, wherein contact region defines a contact region cross section having contact region side walls and a contact region bottom wall, and wherein contact region side walls and contact region bottom wall are defined by a first surface of charge storage lamina.

But Radosevich does not disclose an electrical contact in contact with said first surface of said second conductive film such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region.

However, Kotaki discloses a storage container structure comprises an electrical contact 16, fig. 10 col. 4 line 68, in contact with said first surface of said second conductive film 14, col. 3 line31, such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region. In addition, Paterson discloses a storage container structure in fig. 2h comprises an electrical contact 30, col. 5 line 28, in contact with said first surface of said second conductive film 24, col. 4 line 38, such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region. At the time the invention was made; it would have been obvious to one of ordinary skill in the art to use the electrical contact teaching of Kotaki and/or Paterson with Radosevich's device, because it would have established an electrical contact with the top plate electrode and/or allowing the programming and reading as taught by Paterson col. 6 lines 1-10.

Regarding claims 4-5, Radosevich discloses a storage container structure comprising: a single substrate 11 including a doped semiconductor structure 12, substrate 11 including a generally planar upper surface, an insulating material 13 disposed over and in contact with said generally planar upper surface of substrate, insulating material 13 including a container region disposed therein (where 14 is

located), container region defining a container cross section having container side walls, a container bottom wall, and a container interior bounded in part by container side walls and said container bottom wall; a patterning stop region 12 including: a lower surface in contact with said generally planar upper surface of said substrate 11, and an upper surface configured to define a substantially entirely of said container cross section; a charge storage lamina 14/15/17 over an interior surface of said container region; said charge storage lamina comprising a first conductive film 14, a second conductive film 17, defining a first surface thereon, and an insulating film 15, disposed intermediate said first and second conductive films 14/17; a contact region (top surface of 17) defined by charge storage lamina, wherein contact region defines a contact region cross section having contact region side walls and a contact region bottom wall, and wherein contact region side walls and contact region bottom wall are defined by a first surface of charge storage lamina.

But Radosevich does not disclose an electrical contact in contact with said first surface of said second conductive film such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region.

However, Kotaki discloses a storage container structure comprises an electrical contact 16, fig. 10 col. 4 line 68, in contact with said first surface of said second conductive film 14, col. 3 line31, such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region. In addition, Paterson discloses a storage container structure in fig. 2h

comprises an electrical contact 30, col. 5 line 28, in contact with said first surface of said second conductive film 24, col. 4 line 38, such that said electrical contact and said charge storage lamina occupy collectively at least a portion of said container region. At the time the invention was made; it would have been obvious to one of ordinary skill in the art to use the electrical contact teaching of Kotaki and/or Paterson with Radosevich's device, because it would have established an electrical contact with the top plate electrode and/or allowing the programming and reading as taught by Paterson col. 6 lines 1-10.

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## Response to Arguments

3. Applicant's arguments with respect to claims 1-5 have been considered but are most in view of the new ground(s) of rejection.

#### Conclusion

4. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the

shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

5. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thao X. Le whose telephone number is (571) 272-1708. The examiner can normally be reached on M-F from 8:00 AM - 4:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Wael M. Fahmy can be reached on (571) 272 -1705. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Thao X. Le Patent Examiner 05 Jan. 2006